MBR340

Preferred Device

Axial Lead Rectifier

. . . employing the Schottky Barrier principle in a large area metal–to–silicon power diode. State–of–the–art geometry features epitaxial construction with oxide passivation and metal overlap contact. Ideally suited for use as rectifiers in low–voltage, high–frequency inverters, free wheeling diodes, and polarity protection diodes.

- Extremely Low V_F
- Low Power Loss/High Efficiency
- Highly Stable Oxide Passivated Junction
- Low Stored Charge, Majority Carrier Conduction

Mechanical Characteristics:

- Case: Epoxy, Molded
- Weight: 1.1 gram (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead and Mounting Surface Temperature for Soldering Purposes: 220°C Max. for 10 Seconds, 1/16″ from case
- Shipped in plastic bags, 500 per bag
- Available Tape and Reeled, 1500 per reel, by adding a “RL’’ suffix to the part number
- Polarity: Cathode indicated by Polarity Band
- Marking: B340

MAXIMUM RATINGS

Rating	Symbol	Max	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	40	V
Average Rectified Forward Current T_A = 65°C ($R_{\theta JA}$ = 28°C/W, P.C. Board Mounting)	I_O	3.0	A
Non–Repetitive Peak Surge Current (Note 1.) (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz, T_L = 75°C)	I_{FSM}	80	A
Operating and Storage Junction Temperature Range (Reverse Voltage Applied)	T_J, T_{stg}	–65 to +150	°C
Peak Operating Junction Temperature (Forward Current Applied)	$T_{J(pk)}$	150	°C

1. Lead Temperature reference is cathode lead 1/32″ from case.

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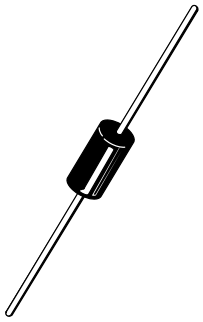
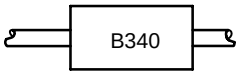
SCHOTTKY BARRIER RECTIFIER 3.0 AMPERES 40 VOLTS



AXIAL LEAD
CASE 267–03
STYLE 1

MARKING DIAGRAM



B340 = Device Code

ORDERING INFORMATION

Device	Package	Shipping
MBR340	Axial Lead	500 Units/Bag
MBR340RL	Axial Lead	1500/Tape & Reel

Preferred devices are recommended choices for future use and best overall value.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient (see Note 3., Mounting Method 3)	$R_{\theta JA}$	28	°C/W

ELECTRICAL CHARACTERISTICS (T_L = 25°C unless otherwise noted) (Note 1.)

Characteristic	Symbol	Max	Unit
Maximum Instantaneous Forward Voltage (Note 2.) (i_F = 1.0 Amp) (i_F = 3.0 Amp) (i_F = 9.4 Amp)	v_F	 0.500 0.600 0.850	V
Maximum Instantaneous Reverse Current @ Rated dc Voltage (Note 2.) T_L = 25°C T_L = 100°C	i_R	 0.60 20	mA

1. Lead Temperature reference is cathode lead 1/32″ from case.
2. Pulse Test: Pulse Width = 300 μs, Duty Cycle = 2.0%.

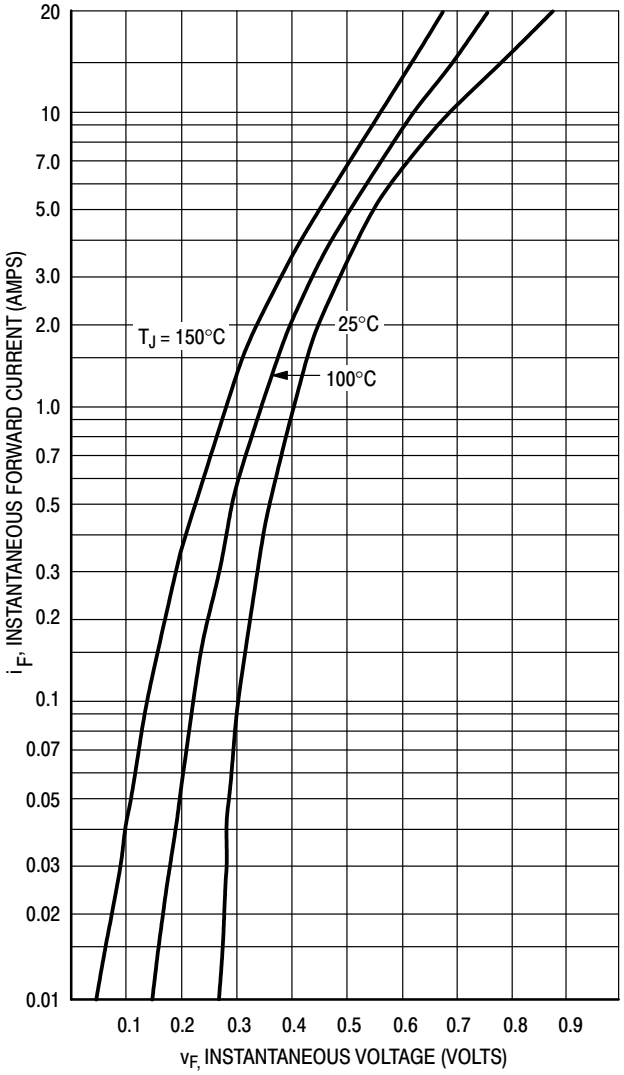


Figure 1. Typical Forward Voltage

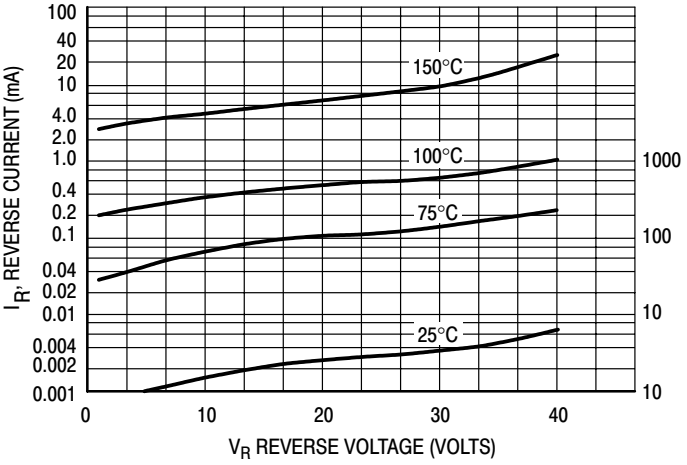


Figure 2. Typical Reverse Current*

*The curves shown are typical for the highest voltage device in the voltage grouping. Typical reverse current for lower voltage selections can be estimated from these same curves if V_R is sufficiently below rated V_R.

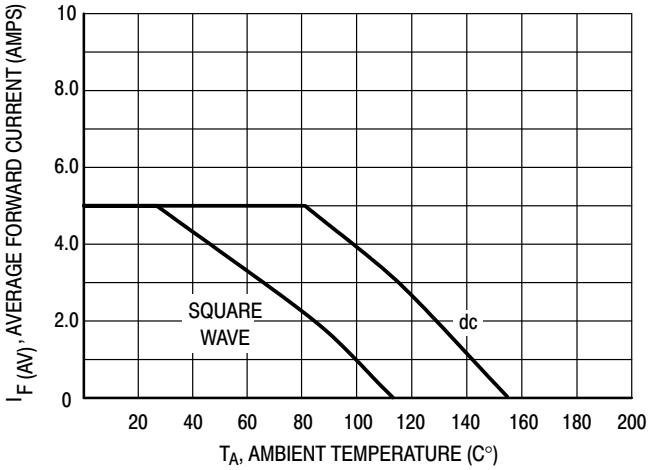


Figure 3. Current Derating (Mounting Method #3 per Note 3.)

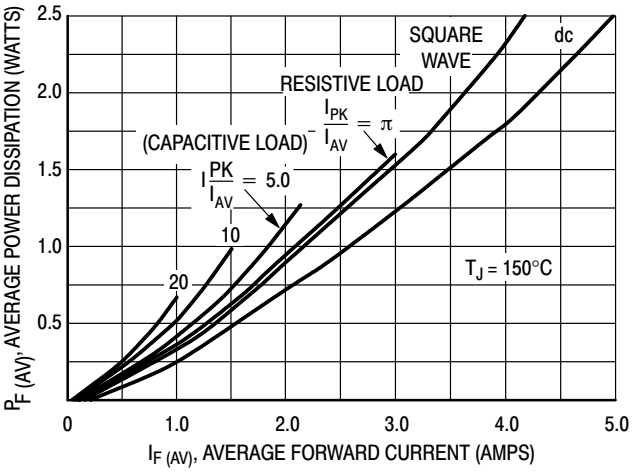


Figure 4. Power Dissipation

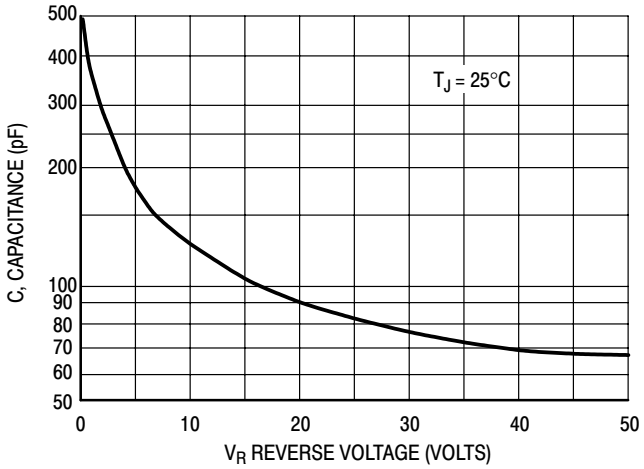


Figure 5. Typical Capacitance

NOTE 3. — MOUNTING DATA

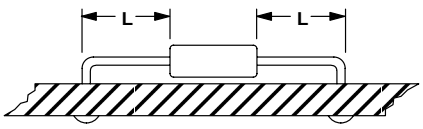
Data shown for thermal resistance junction–to–ambient ($R_{\theta JA}$) for the mountings shown is to be used as typical guideline values for preliminary engineering, or in case the tie point temperature cannot be measured.

TYPICAL VALUES FOR $R_{\theta JA}$ IN STILL AIR

Mounting Method	Lead Length, L (in)				$R_{\theta JA}$
	1/8	1/4	1/2	3/4	
1	50	51	53	55	°C/W
2	58	59	61	63	°C/W
3	28				°C/W

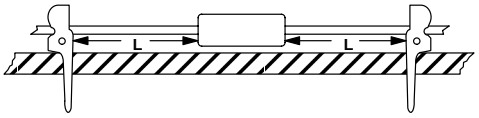
Mounting Method 1

P.C. Board where available copper surface is small.



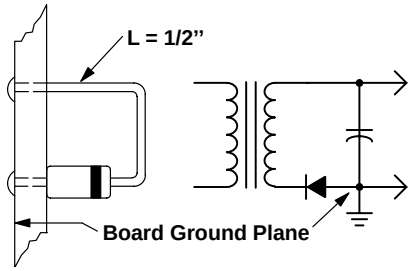
Mounting Method 2

Vector Push–In Terminals T–28



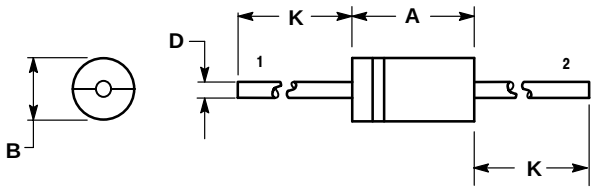
Mounting Method 3

P.C. Board with 2–1/2″ X 2–1/2″ copper surface.



PACKAGE DIMENSIONS

AXIAL LEAD
CASE 267–03
ISSUE G



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	0.370	0.380	9.40	9.65
B	0.190	0.210	4.83	5.33
D	0.048	0.052	1.22	1.32
K	1.000	---	25.40	---

STYLE 1:
PIN 1. CATHODE (POLARITY BAND)
2. ANODE

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